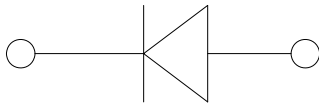
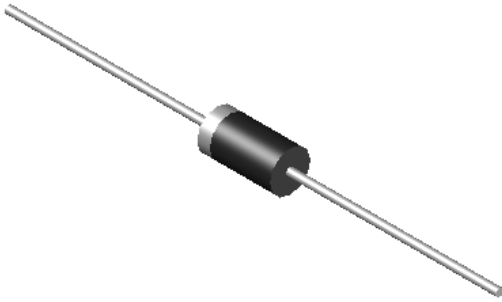




High Efficient Rectifier



Features

- High efficiency
- High current capability
- High Reliability
- High surge current capability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Mechanical Data

- **Package:** DO-201AD(DO-27)
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** Color band denotes cathode end

■Maximum Ratings (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	HER501	HER502	HER503	HER504	HER505	HER506	HER507	HER508
Device marking code			HER501	HER502	HER503	HER504	HER505	HER506	HER507	HER508
Repetitive Peak Reverse Voltage	V _{RRM}	V	50	100	200	300	400	600	800	1000
Average Forward Current @60Hz sine wave, Resistance load, T _a =50°C	I _O	A	5.0							
Surge(Non-repetitive)Forward Current @60Hz Half-sine wave, 1 cycle, T _a =25°C	I _{FSM}	A	150							
Storage Temperature	T _{stg}	°C	-55 ~+150							
Junction Temperature	T _j	°C	-55~+125							

■Electrical Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	HER501	HER502	HER503	HER504	HER505	HER506	HER507	HER508
Maximum instantaneous forward voltage drop per diode	V _{FM}	V	IFM=5.0A	1.0			1.3		1.7		
Maximum DC reverse current at rated DC blocking voltage per diode	I _{RRM1}	μA	T _a =25°C	2.5							
	I _{RRM2}		T _a =100°C	150							
Reverse Recovery time	t _{rr}	ns	I _F =0.5A I _R =1A I _{RR} =0.25A	50					75		
Typical junction capacitance	C _j	pF	Measured at 1MHZ and Applied Reverse Voltage of 4.0 V.D.C.	85					60		

■Thermal Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	HER501	HER502	HER503	HER504	HER505	HER506	HER507	HER508
Thermal Resistance(Typical)	R _{θJA}	°C/W	15							



HER501 THRU HER508

■ Ordering Information (Example)

PREFERRED P/N	PACKAGE CODE	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
HER501~HER508	D1	Approximate 1.05	1250	1250	12500	Tape
HER501~HER508	C1	Approximate 1.05	250	250	12500	Bulk

■ Characteristics (Typical)

FIG.1: Io-Ta Curve

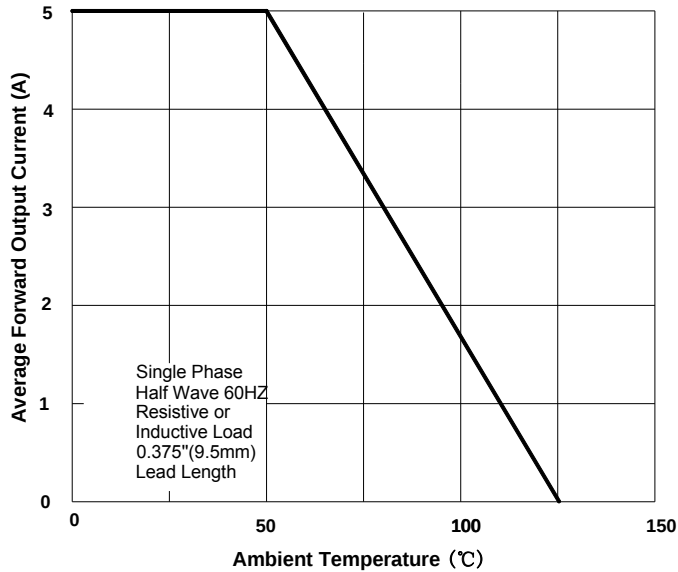


FIG.2: Surge Forward Current Capability

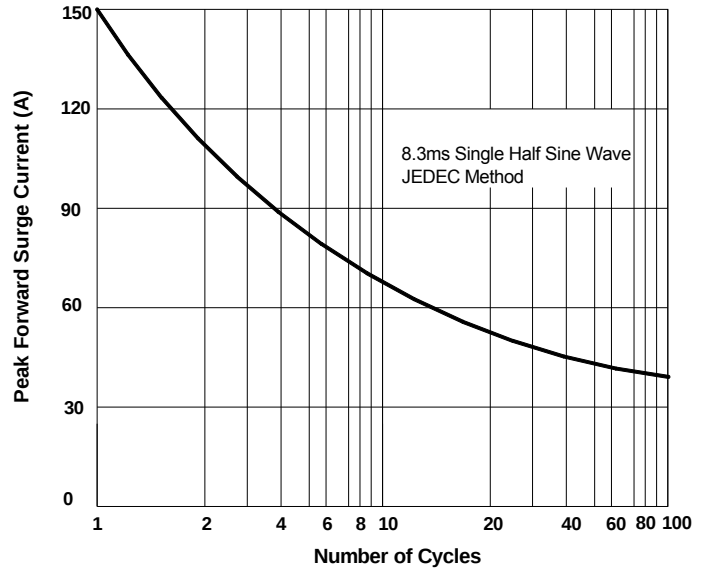


FIG.3: Forward Voltage

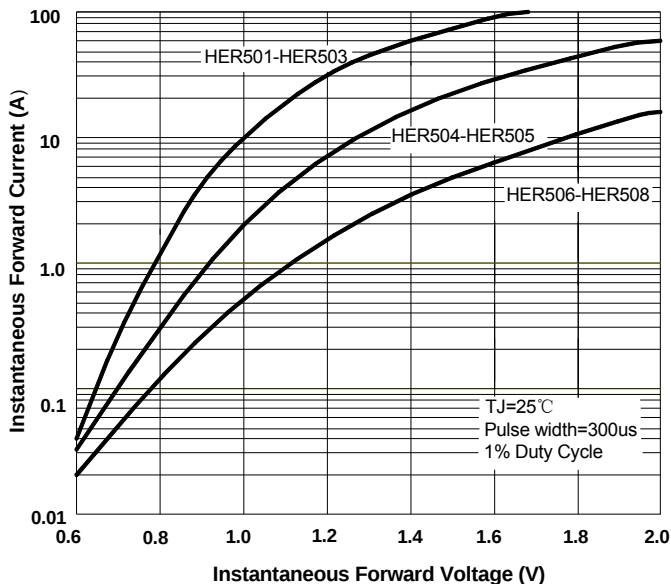


FIG.4: Typical Reverse Characteristics

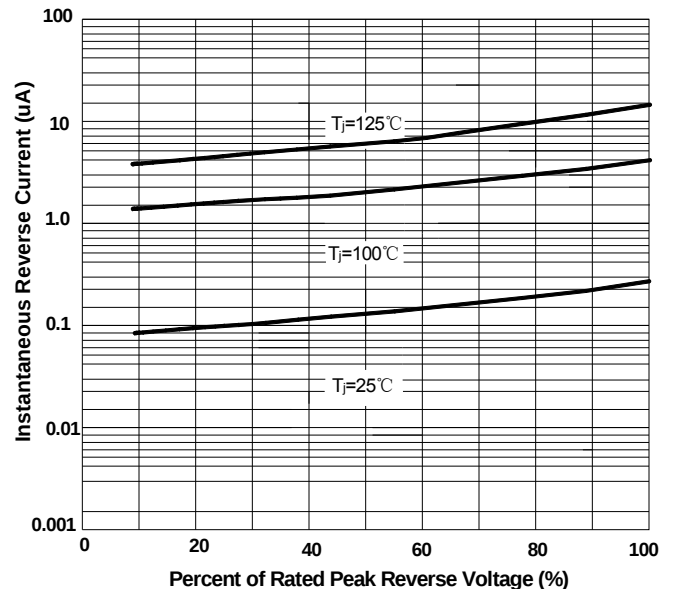
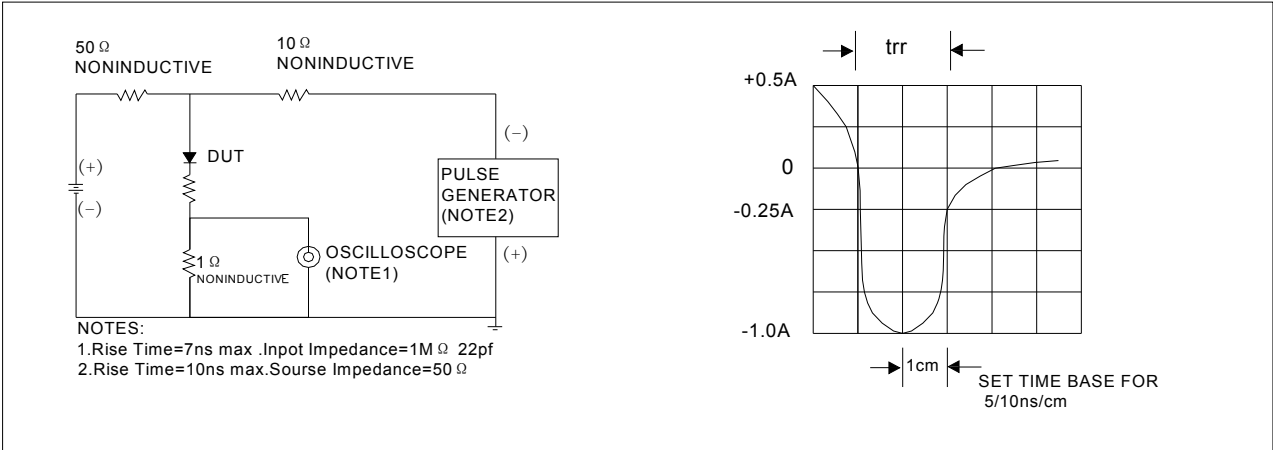
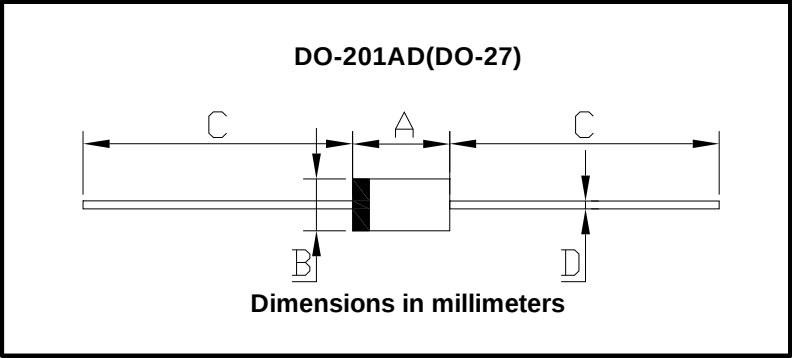


FIG.5: Diagram of circuit and Testing wave form of reverse recovery time



■ Outline Dimensions



DO-201AD(DO-27)		
Dim	Min	Max
A	8.50	9.50
B	5.00	5.60
C	25.4	/
D	1.20	1.30



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